

an interlayer insulating film interposed between the active matrix substrate and the plurality of pixel electrodes, wherein one of said two layers has a first porous surface and the other one of said two layers has a second porous surface, and said two layers have concavities and convexities.

8. (Amended) A reflection type liquid crystal display device comprising:

at least one thin film transistor formed over an active matrix substrate;

a pixel electrode connecting to said thin film transistor;

an interlayer insulating film formed between said thin film transistor and said pixel electrode;

a light reflective film formed of at least two layers on said pixel electrode, wherein an upper surface of said light reflective film is porous, and has concavities and convexities;

a first orientation film formed at least on said light reflective film;

a color filter comprising red, green and blue [formed over] adjacent to an opposing substrate;

an opposing electrode [formed over] adjacent to said opposing substrate;

porous surface

10<sup>5</sup> - 10<sup>6</sup> nm

2 a second orientation film [formed over] adjacent to  
said opposing substrate; and  
a liquid crystal material injected between said first  
and second orientation film[,  
[wherein said reflection type liquid crystal display  
device has a reflectance of 80 % or less].

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Sub FI 3 11. (Amended) A liquid crystal display device of claim 8,  
wherein [said] a reflectance is 70 % or more when an applied  
voltage is 5V to 15V.

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Sub D4 14. (Amended) A reflection type liquid crystal display  
device comprising:  
a thin film transistor [on] over a substrate having an  
insulating surface;  
an interlayer insulating film comprising a material  
selected from the group consisting of silicon oxide, silicon  
nitride and an organic resin on said thin film transistor;  
a pixel electrode connected to said thin film  
transistor; and  
a light reflective film formed of at least two layers  
on said pixel electrode,

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wherein one of said two layers has a first porous surface and the other one of said two layers has a second porous surface, and said two layers have concavities and convexities [, and

[wherein said reflection type liquid crystal display device has a reflectance of 80 % or less].

Sub F1  
18. (Amended) A liquid crystal display device of claim 14, wherein [said] a reflectance is 70 % or more when an applied voltage is 5V to 15V.

Sub D4  
19. (Amended) A reflection type liquid crystal display device comprising:  
at least one thin film transistor formed over an active matrix substrate;  
a pixel electrode connecting to said thin film transistor;  
an interlayer insulating film formed between said thin film transistor and said pixel electrode;  
a light reflective film formed on said pixel electrode, wherein an upper surface of said light reflective film is porous, and has concavities and convexities;

a first orientation film formed at least on said light reflective film;

a color filter comprising red, green and blue [formed over] adjacent to an opposing substrate;

an opposing electrode [formed over] adjacent to said opposing substrate;

a second orientation film [formed over] adjacent to said opposing substrate; and

a liquid crystal material injected between said first and second orientation film.

23. (Amended) A reflection type liquid crystal display device comprising:

a thin film transistor [on] over a substrate having an insulating surface;

an interlayer insulating film comprising a material selected from the group consisting of silicon oxide, silicon nitride and an organic resin on said thin film transistor;

a pixel electrode connected to said thin film transistor; and

a light reflective film formed on said pixel electrode,